

To all our customers

Regarding the change of names mentioned in the document, such as Hitachi Electric and Hitachi XX, to Renesas Technology Corp.

The semiconductor operations of Mitsubishi Electric and Hitachi were transferred to Renesas Technology Corporation on April 1st 2003. These operations include microcomputer, logic, analog and discrete devices, and memory chips other than DRAMs (flash memory, SRAMs etc.) Accordingly, although Hitachi, Hitachi, Ltd., Hitachi Semiconductors, and other Hitachi brand names are mentioned in the document, these names have in fact all been changed to Renesas Technology Corp. Thank you for your understanding. Except for our corporate trademark, logo and corporate statement, no changes whatsoever have been made to the contents of the document, and these changes do not constitute any alteration to the contents of the document itself.

Renesas Technology Home Page: <http://www.renesas.com>

Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

Cautions

Keep safety first in your circuit designs!

1. Renesas Technology Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage.

Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

Notes regarding these materials

1. These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corporation product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corporation or a third party.
2. Renesas Technology Corporation assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials.
3. All information contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Renesas Technology Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact Renesas Technology Corporation or an authorized Renesas Technology Corporation product distributor for the latest product information before purchasing a product listed herein.
The information described here may contain technical inaccuracies or typographical errors. Renesas Technology Corporation assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors.
Please also pay attention to information published by Renesas Technology Corporation by various means, including the Renesas Technology Corporation Semiconductor home page (<http://www.renesas.com>).
4. When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision on the applicability of the information and products. Renesas Technology Corporation assumes no responsibility for any damage, liability or other loss resulting from the information contained herein.
5. Renesas Technology Corporation semiconductors are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact Renesas Technology Corporation or an authorized Renesas Technology Corporation product distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
6. The prior written approval of Renesas Technology Corporation is necessary to reprint or reproduce in whole or in part these materials.
7. If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination.
Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.
8. Please contact Renesas Technology Corporation for further details on these materials or the products contained therein.

HD151BF854

2.5 V PLL Clock Buffer for DDR Application



ADE-205-696D (Z)

Preliminary
Rev.4
Jan. 2003

Description

The HD151BF854 is a high-performance, low-skew, low-jitter, PLL clock buffer. It is specifically designed for use with DDR (Double Data Rate) PC mother board application.

Features

- Designed for DDR200/266/333/400 PC mother board clock buffering
- Supports 60 MHz to 210 MHz operation range
- Distributes one to six differential clock outputs pairs
- Spread spectrum clock compatible
- External feedback pin (FBIN) is used to synchronize the outputs to the clock input
- Supports 2.5 V analog supply voltage (AVDD), and 2.5 V VDD
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD151BF854SSEL	SSOP-28 pin	SSOP-28	SS	EL (1,000 pcs / Reel)

Note: Please consult the sales office for the above package availability.

Key Specifications

- Supply voltages: $VDD = AVDD = 2.5\text{ V} \pm 0.2\text{ V}$
- Output clock cycle to cycle jitter = $\pm 75\text{ ps}$
- Output clock pin to pin skew = 150 ps

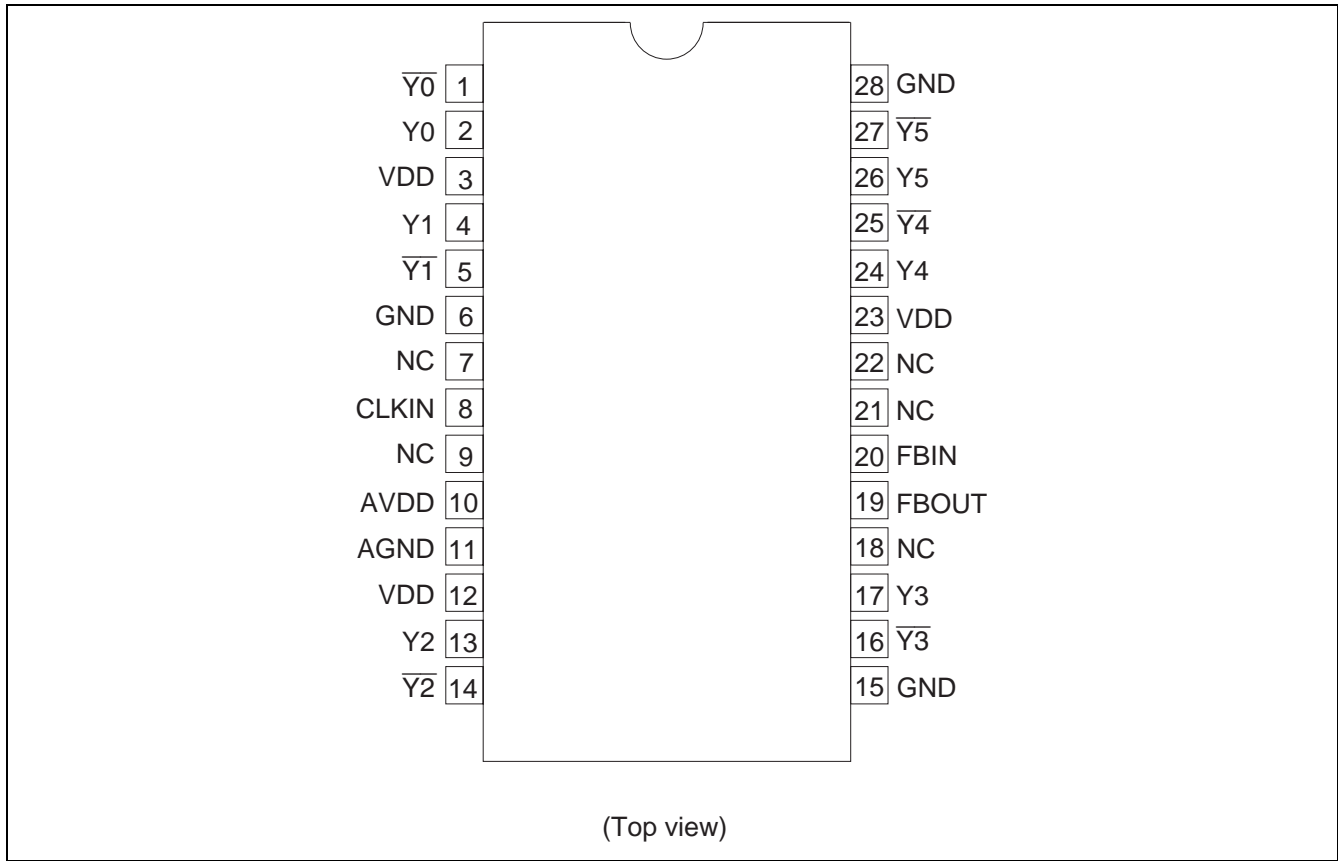
Function Table

Inputs		Outputs			
AVDD	CLK	Yn	\overline{Yn}	FBOUT	PLL
GND	L	L	H	L	Bypass / Off
GND	H	H	L	H	Bypass / Off
2.5 V (typ.)	L	L	H	L	Running
2.5 V (typ.)	H	H	L	H	Running

H: High level

L: Low level

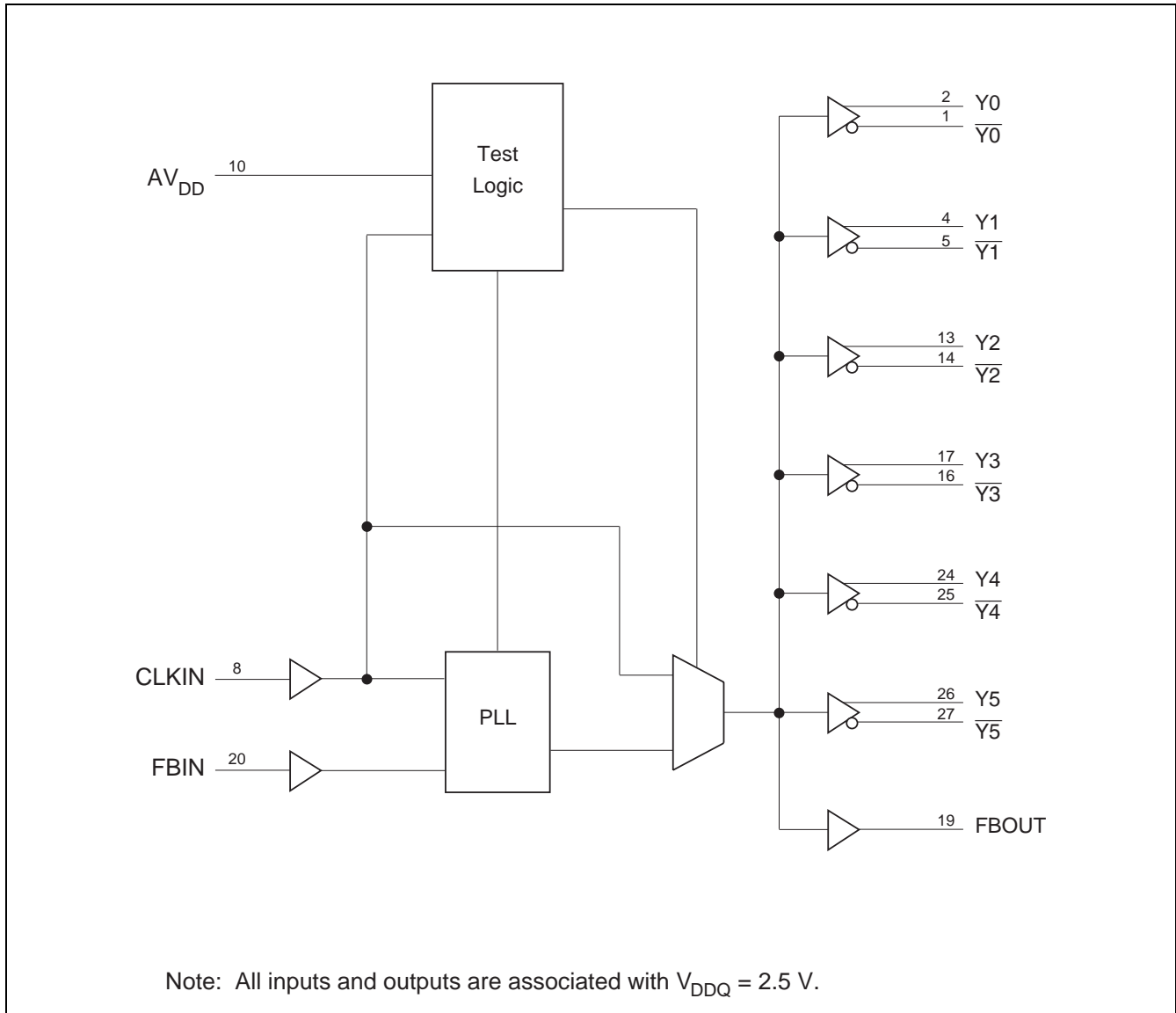
Pin Arrangement



Pin Functions

Pin name	No.	Type	Description
AGND	11	Ground	Analog ground. AGND provides the ground reference for the analog circuitry.
AVDD	10	Power	Analog power supply. AVDD provides the power reference for the analog circuitry. In addition, AVDD can be used to bypass the PLL for test purposes. When AVDD is strapped to ground, PLL is bypassed and CLK is buffered directly to the device outputs.
CLKIN	8	Input	Clock input. CLKIN provides the clock signal to be distributed by the HD151BF854 clock buffer. CLK is used to provide the reference signal to the integrated PLL that generates the clock output signals. CLK must have a fixed frequency and fixed phase for the PLL to obtain phase lock. Once the circuit is powered up and a valid CLK signal is applied, a stabilization time is required for the PLL to phase lock the feedback signal to its reference signal.
FBIN	20	Input	Feedback input. FBIN provides the feedback signal to the internal PLL. FBIN must be hard-wired to FBOUT to complete the PLL. The integrated PLL synchronizes CLKIN and FBIN so that there is nominally zero phase error between CLKIN and FBIN.
FBOUT	19	Output	Feedback output. FBOUT is dedicated for external feedback. It switches at the same frequency as CLK. When externally wired to FBIN, FBOUT completes the feedback loop of the PLL.
GND	6, 15, 28	Ground	Ground
VDD	3, 12, 23	Power	Power supply
Y	2, 4, 13, 17, 24, 26	Output	Clock outputs. (+Clock) These outputs provide low-skew copies of CLK.
\bar{Y}	1, 5, 14, 16, 25, 27	Output	Bar clock outputs. (-Clock) These outputs provide low-skew copies of CLK.
NC	7, 9, 18, 21, 22	NC	Don't connect any VDD or GND.

Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	VDD	-0.5 to 3.6	V	
Input voltage	V _{IC}	-0.5 to 3.6	V	CLKIN
	V _I	-0.5 to VDD+0.5	V	
Output voltage *1	V _O	-0.5 to VDD+0.5	V	
Input clamp current	I _{IK}	-50	mA	V _I < 0
Output clamp current	I _{OK}	-50	mA	V _O < 0
Continuous output current	I _O	±50	mA	V _O = 0 to VDD
Maximum power dissipation at Ta = 55°C (in still air)		0.7	W	
Storage temperature	T _{stg}	-65 to +150	°C	

Notes: Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

1. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit	Conditions
Supply voltage	AVDD	2.3	2.5	2.7	V	
Output supply voltage	VDD	2.3	2.5	2.7	V	
DC input signal voltage		-0.3	—	VDD+0.3	V	All pins
High level input voltage	V _{IH}	1.7	—	3.6	V	CLKIN
High level input voltage	V _{IH}	1.7	—	VDD+0.3	V	FBIN
Low level input voltage	V _{IL}	-0.3	—	0.7	V	CLKIN, FBIN
Output differential cross point voltage	V _{OX}	0.5×VDD -0.2	—	0.5×VDD +0.2	V	
Output current	I _{OH}	—	—	-12	mA	
	I _{OL}	—	—	12		
Input clock slew rate	SR	1	—	—	V/ns	
Operating temperature	T _a	0	—	70	°C	

Note: Unused inputs must be held high or low to prevent them from floating.

Electrical Characteristics

Item	Symbol	Min	Typ * ¹	Max	Unit	Test Conditions
Input clamp voltage (All inputs)	V _{IK}	—	—	-1.2	V	I _I = -18 mA, VDD = 2.3 V
Output voltage	V _{OH}	VDD-0.2	—	—	V	I _{OH} = -100 μA, VDD = 2.3 to 2.7 V
		1.7	—	VDD		I _{OH} = -12 mA, VDD = 2.3 V
	V _{OL}	—	—	0.2		I _{OL} = 100 μA, VDD = 2.3 to 2.7 V
		—	—	0.6		I _{OL} = 12 mA, VDD = 2.3 V
Input current	I _I	-10	—	10	μA	V _I = 0 V or 2.7 V, VDD = 2.7 V, CLKIN, FBIN
Analog supply current	A _{ICC}	—	—	12	mA	VDD = AVDD = 2.7 V, 170 MHz
Dynamic supply current	D _{ICC}	—	250	300	mA	VDD = AVDD = 2.7 V, 170 MHz All Y _n , \overline{Y}_n , = open
Input capacitance* ²	C _I	2.5	—	3.5	pF	CLKIN and FBIN
Delta input capacitance* ²	C _{Di}	-0.25	—	0.25	pF	

- Notes: 1. For conditions shown as Min or Max, use the appropriate value specified under recommended operating conditions.
 2. Target of design, not 100% tested in production.

Switching Characteristics

Ta = 25°C, VDD = AVDD = 2.5V

Item	Symbol	Min	Typ	Max	Unit	Test Conditions & Notes
Period jitter	t _{PER}	—	75	—	ps	*7, 8
Half period jitter	t _{HPER}	—	120	—	ps	*8
Cycle to cycle jitter	t _{CC}	—	75	—	ps	
Static phase offset	t _{SPE}	—	150	—	ps	*4, 5
Output clock skew	t _{sk}	—	150	—	ps	
Operating clock frequency	f _{CLK(O)}	60	—	210	MHz	*1, 2
Application clock frequency	f _{CLK(A)}	80	166	210	MHz	*1, 3
Slew rate		1.0	—	2.0	V/ns	20% to 80%
Stabilization time		—	—	0.1	ms	*6

Notes: Target of design, not 100% tested in production.

1. The PLL must be able to handle spread spectrum induced skew. (the specification for this frequency modulation can be found in the latest Intel PC100 Registered DIMM specification)
2. Operating clock frequency indicates a range over which the PLL must be able to lock, but in which it is not required to meet the other timing parameters. (Used for low speed system debug.)
3. Application clock frequency indicates a range over which the PLL must meet all timing parameters.
4. Assumes equal wire length and loading on the clock output and feedback path.
5. Static phase offset does not include jitter.
6. Stabilization time is the time required for the integrated PLL circuit to obtain phase lock of it's feedback signal to it's reference signal after power on.
7. Period jitter defines the largest variation in clock period, around a nominal clock period.
8. Period jitter and half period jitter are separate specifications that must be met independently of each other.

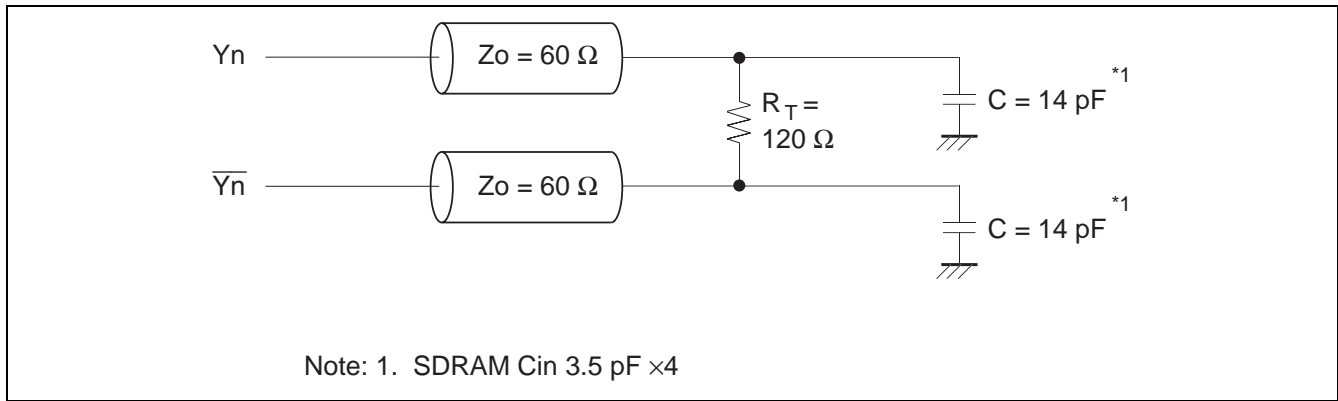


Figure 1 Clock outputs test circuit

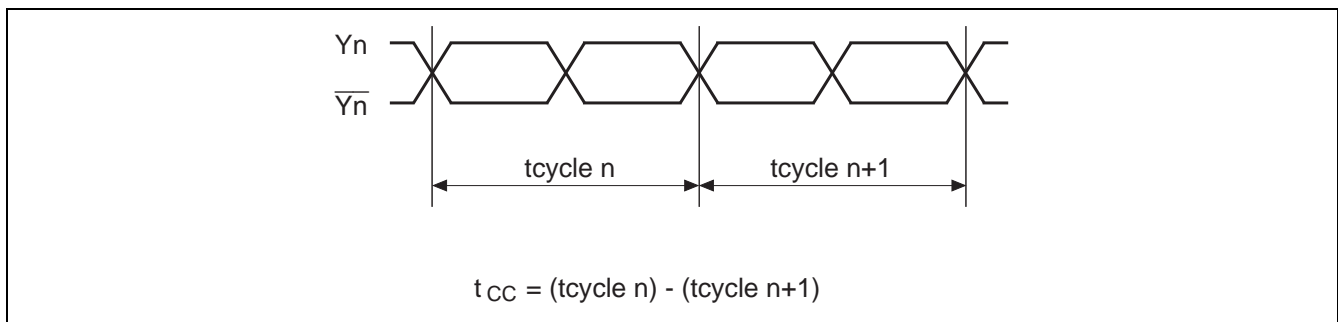


Figure 2 Cycle to cycle jitter

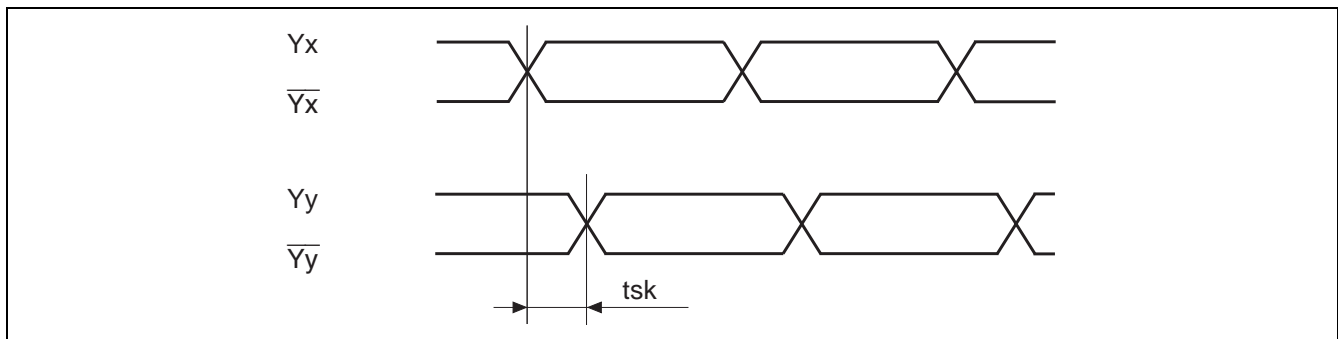
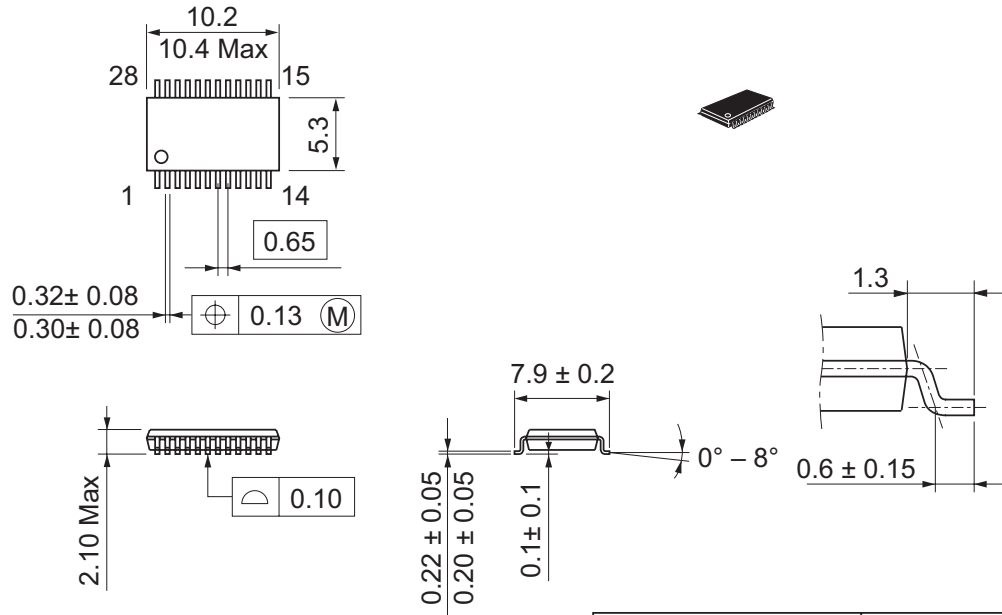


Figure 3 Output clock skew (Differential clock output)

Package Dimensions

Unit : mm



Dimension including the plating thickness
Base material dimension

Hitachi Code	SSOP-28
JEDEC	—
EIAJ	—
Weight (reference value)	

Disclaimer

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

Sales Offices

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: (03) 3270-2111 Fax: (03) 3270-5109

URL <http://www.hitachisemiconductor.com/>

For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe Ltd.
Electronic Components Group
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 778322

Hitachi Europe GmbH
Electronic Components Group
Dornacher Str 3
D-85622 Feldkirchen
Postfach 201, D-85619 Feldkirchen
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Asia Ltd.
Hitachi Tower
16 Collyer Quay #20-00
Singapore 049318
Tel: <65>-6538-6533/6538-8577
Fax: <65>-6538-6933/6538-3877
URL: <http://semiconductor.hitachi.com.sg>

Hitachi Asia Ltd.
(Taipei Branch Office)
4/F, No. 167, Tun Hwa North Road
Hung-Kuo Building
Taipei (105), Taiwan
Tel: <886>-(2)-2718-3666
Fax: <886>-(2)-2718-8180
Telex: 23222 HAS-TP
URL: <http://semiconductor.hitachi.com.tw>

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon Hong Kong
Tel: <852>-2735-9218
Fax: <852>-2730-0281
URL: <http://semiconductor.hitachi.com.hk>

Copyright © Hitachi, Ltd., 2003. All rights reserved. Printed in Japan.

Colophon 7.0